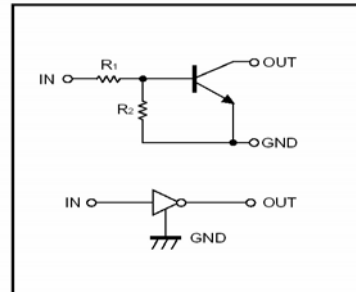


FEATURES

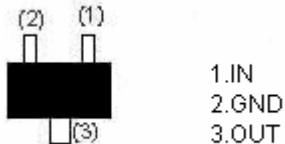
- * Built-in bias resistors enable the configuration of an inverter circuit without connecting input resistors (see equivalent circuit).
- * Only the on/off conditions need to be set for operation, making device design easy.
- * The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input. They also have the advantage of almost completely eliminating parasitic effects.

●Equivalent circuit



PIN CONNECTIONS AND MARKING

DTC123JE



SOT-523

Abbreviated symbol: E42

DTC123JUA



SOT-323

Abbreviated symbol: E42

DTC123JKA



SOT-23-3L

Abbreviated symbol: E42

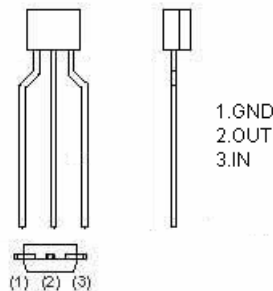
DTC123JCA



SOT-23

Abbreviated symbol: E42

DTC123JSA



TO-92S

Absolute maximum ratings(Ta=25°C)

Parameter	Symbol	Limits (DTC123J□)					Unit
		E	UA	KA	CA	SA	
Supply voltage	V _{CC}	50					V
Input voltage	V _{IN}	-5~12					V
Output current	I _O	100					mA
	I _{C(MAX)}	100					
Power dissipation	P _d	150		200		300	mW
Junction temperature	T _J	150					°C
Storage temperature	T _{stg}	-55~150					°C

Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ	Max.	Unit	Conditions
Input voltage	V _{I(off)}			0.5	V	V _{CC} =5V, I _O =100μA
	V _{I(on)}	1.1				V _O =0.3V, I _O =5 mA
Output voltage	V _{O(on)}		0.1	0.3	V	I _O /I _I =5mA/0.25mA
Input current	I _I			3.6	mA	V _I =5V
Output current	I _{O(off)}			0.5	μA	V _{CC} =50V, V _I =0
DC current gain	G _I	80				V _O =5V, I _O =10mA
Input resistance	R ₁	1.54	2.2	2.86	KΩ	-
Resistance ratio	R ₂ /R ₁	17	21	26		-
Transition frequency	f _T		250		MHz	V _O =10V, I _O =-5mA, f=100MHz

Typical Characteristics

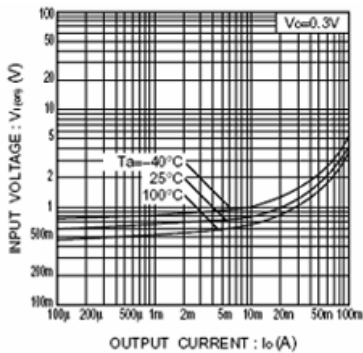


Fig.1 Input voltage vs. output current (ON characteristics)

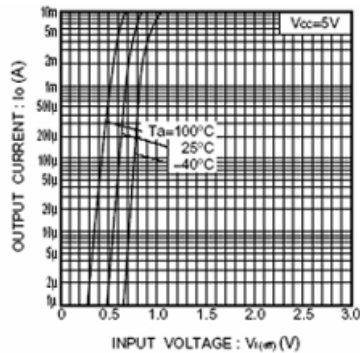


Fig.2 Output current vs. input voltage (OFF characteristics)

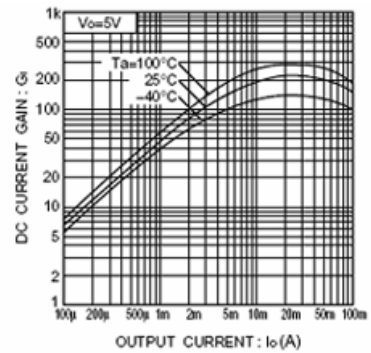


Fig.3 DC current gain vs. output current

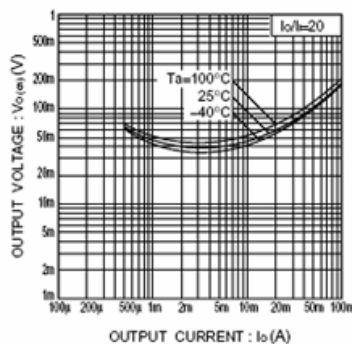


Fig.4 Output voltage vs. output current